



## MBRF20H100CT – MBRF20H200CT Isolated 20.0 AMPS. Schottky Barrier Rectifiers ITO-220AB



### **Features**

- ∻ Plastic material used carries Underwriters Laboratory Classifications 94V-0
- ∻ Metal silicon junction, majority carrier conduction
- ∻ Low power loss, high efficiency
- High current capability, low forward voltage drop ∻
- ∻ High surge capability
- For use in low voltage, high frequency inverters, free ∻ wheeling, and polarity protection applications
- ∻ Guardring for overvoltage protection
- ∻ High temperature soldering guaranteed: 260°C/10 seconds,0.25"(6.35mm)from case

# Mechanical Data

- ∻ Cases: ITO-220AB molded plastic
- ∻ Terminals: Pure tin plated, lead free. solderable per MIL-STD-750, Method 2026
- ⊹ Polarity: As marked
- ∻ Mounting position: Any
- ∻
- Mounting torque: 5 in. Ibs. max Weight: 0.08 ounce, 2.24 grams ♦

# **Maximum Ratings and Electrical Characteristics**

Rating at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load.

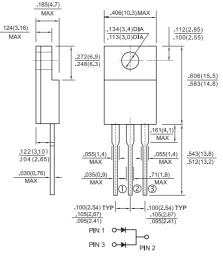
For capacitive load, derate current by 20%

Type Number	Symbol	MBRF 20H100CT	MBRF 20H150CT	MBRF 20H200CT	Units
Maximum Recurrent Peak Reverse Voltage	V <sub>RRM</sub>	100	150	200	V
Maximum RMS Voltage	V <sub>RMS</sub>	70	105	140	V
Maximum DC Blocking Voltage	V <sub>DC</sub>	100	150	200	V
Maximum Average Forward Rectified Current at $T_c$ =133°C	I <sub>(AV)</sub>	20			А
Peak Repetitive Forward Current (Rated $V_R$ , Square Wave, 20KHz) at Tc=133°C	I <sub>FRM</sub>	20			А
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I <sub>FSM</sub>	150			А
Peak Repetitive Reverse Surge Current (Note 1)	I <sub>RRM</sub>	1.0 0.5		А	
Maximum Instantaneous Forward Voltage at (Note 2) I <sub>F</sub> = 10A, Tc=25°C I <sub>F</sub> = 10A, Tc=125°C I <sub>F</sub> =20A, Tc=25°C I <sub>F</sub> =20A, Tc=125°C	V <sub>F</sub>	0.85 0.75 0.95 0.85	0.88 0.75 0.97 0.85		V
Maximum Instantaneous Reverse Current at Rated DC Blocking Voltage @Tc=25 °C @ Tc=125 °C	I <sub>R</sub>	5.0 2.0		uA mA	
Voltage Rate of Change, (Rated $V_R$ )	dV/dt	10,000			V/uS
$\begin{array}{l} \text{RMS Isolation Voltage (t=1.0 second, R.H.} \\ \leq 30\%, \ T_{\text{A}} = 25 \ ^{\circ}\text{C}) & (\text{Note 4}) \\ & (\text{Note 5}) \\ & (\text{Note 6}) \end{array}$	V <sub>ISO</sub>	4500 3500 1500			v
Typical Thermal Resistance Per Leg (Note3)	R <sub>θJC</sub>	3.5			°C/W
Operating Junction Temperature Range	TJ	-65 to +175			°C
Storage Temperature Range	TSTG	-65 to +175			°C
Notes: 1. 2.0 us Pulse Width, f=1.0 KHz		2. Pulse Test: 3	00us Pulse Width	, 1% Duty Cycle	

- 1. 2.0 us Pulse Width, f=1.0 KHz 3. Thermal Resistance from Junction to Case Per Leg.
- 4. Clip Mounting (on case), where lead does not overlap heatsink with 0.110" offset.

5. Clip mounting (on case), where leads do overlap heatsink.

6. Screw mounting with 4-40 screw, where washer diameter is  $\leq$  4.9 mm (0.19")



Dimensions in inches and (millimeters)

Marking Diagram



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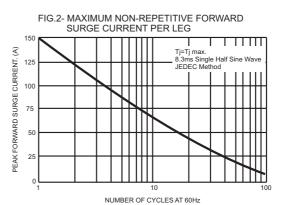
- MBRF20HXXXCT = Specific Device Code
  - = Year = Work Week

Version: C09



#### FIG.1- FORWARD CURRENT DERATING CURVE 2 RESISTIVE OR INDUCTIVE LOAD AVERAGE FORWARD CURRENT. (A) 16 12 8 0 50 75 100 150 25 125 175 CASE TEMPERATURE. (°C) FIG.3- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS PER LEG 40 10 € INSTANTANEOUS FORWARD CURRENT. Tj=125° 0. - w Pı dth 30 1% Duty Cycle 0.01 0.2 0.3 0.4 0.5 0.6 0.7 0.8 0.9 1.0 1.1 1.2 0.1 0 FORWARD VOLTAGE. (V) FIG.5- TYPICAL JUNCTION CAPACITANCE PER LEG 5,000

92,000 JUNCTION CAPACITANCE. 2000 2000 2000 Ш ₩ 100 L 0.1 1.0 10 100 REVERSE VOLTAGE. (V)



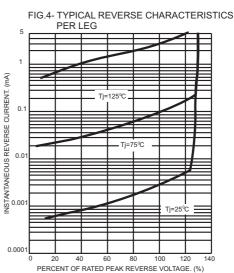
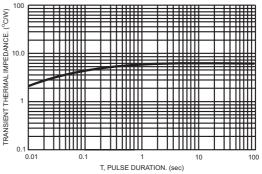


FIG.6- TYPICAL TRANSIENT THERMAL IMPEDANCE PER LEG



#### RATINGS AND CHARACTERISTIC CURVES(MBRF20H100CT - MBRF20H200CT)

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